The Effects of Temperature on the Gain Profile of THz Quantum Cascade Lasers

Rikard Nelander and Andreas Wacker

Mathematical Physics, Lund University

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R. Nelander, A. Wacker (Lund Univ.)

What is limiting high temperature operation of THz QCLs?

Theoretical investigation of a THz QCL.

- Discuss the method.
- Present results.
- Try to interpret results.

What can be done to increase the temperature range?



Non-Equilibrium Green's Functions

• Main advantage: BROADENING. Extension of the density matrix:

$$ho_{lphaeta}({f k})=-{
m i}\int {{
m d} E\over 2\pi}G^<_{lphaeta}({f k},E)$$

- Scattering due to Impurities, Interface roughness, Optical and Acoustic phonons, and also electron-electron interaction.
- No fitting parameters are used, only well-known material parameters.



The Calculation Procedure

Or Calculate the eigenstates states of the periodic laser structure.

Theory

- Iterate to self-consistency:
 - Evaluate the Self-energies from the Greens functions.
 - Evaluate new Green's Function using the Dyson Equation and the Keldysh Relation.
- The gain is calculated from the steady-state solution to the transport problem.



The Device

Conduction Band Profile

Resonant phonon depopulation design from the MIT group.



- Doping density $N_{\rm D} = 2.25 \times 10^{10} \ {\rm cm}^{-2}$.
- Emitting at 1.9 THz (7.9 meV).
- Lasing transition between state 4 and 3.
- Laser operation up to 110 K pulsed, 95 K cw.



Presented in S. Kumar et. al. APL 88, 121123 (2006).

Gain



Strong decrease of peak with increasing gain temperature.

Increased broadening of both gain and absorption peak.

Bias 46.5 mV/period.



Broadening and Overlap - Simple Model

Lorentzian peaks:

$$g(E) = \frac{1}{\pi} \frac{\gamma}{E^2 + \gamma^2}$$

where γ is the width.

Reduction *both* due to broadening and overlap.



Population inversion



50 % reduction in inversion from low temperature to 100 K.

The increased population in the lower laser state is due to thermal backfilling.



Population inversion (2)

Gain at the lasing energy and the population inversion.



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Gain at the lasing energy and the population inversion.



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Temperature Dependent Effects

Temperature enters our calculation in three ways:

- Optical phonon scattering. Emission is proportional to $n_B(\hbar\omega_{opt}) + 1$. At T = 100 K, $n_B(\hbar\omega_{opt}) \sim 10^{-2}$ in GaAs.
- Acoustic phonon scattering. Very weak coupling.
- *Impurity scattering*. Strongly influenced by the screening of ionised dopants by electrons. A common approach is the Debye-approximation,

$$V_{
m eff}(r) = V_{
m coul}(r) {
m e}^{-\lambda_{
m Debye} r}$$

and where the screening length is temperature dependent,

$$\lambda_{\rm Debye}^2 = \frac{e^2 n_{\rm 3D}}{\epsilon_s \epsilon_0 k_B T}.$$

A hot electron gas is less affected by the impurity potential \implies Less screening and more scattering.

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The γ -factors

Used when calculating the self energies

$$\Sigma_{lphalpha'}(\mathbf{k}, E) = \sum_{etaeta'} \sum_{\mathbf{k}'} \gamma^{\mathrm{elast}}_{lphalpha'etaeta'}(\mathbf{k} - \mathbf{k}') G_{etaeta'}(\mathbf{k}', E)$$

where the rate $W_{\alpha
ightarrow eta} = rac{2\pi}{\hbar} \gamma_{lpha lpha eta eta}$



- Strong increase in the impurity scattering.
- Optical phonon emission is almost constant.
- $\gamma^{\rm ac}_{\rm 3333}=$ 3.8 $\mu {\rm eV}$ at 100 K.



Outlook

Can one reduce scattering from ionised dopants?

- Increase the energy of state 5 to reduce spectral overlap with the gain transition.
- The Debye screening length $l_{\rm Debye}=1/\lambda_{\rm Debye}=$ 39 nm at 100 K, the laser period length is 55.4 nm.
- Higher doping?

$$\Delta n \propto N_D$$
 $\gamma \propto N_D$ $I_{\rm Debye} \propto \sqrt{T/N_D}$

Outlook - Simulation

- Screening of impurities is a complex many-body problem.
- Screening in electron-electron scattering should be just as important.

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Conclusion

The NEGF simulation of a THz QCL has shown that:

- A substantial population inversion remains at maximum lasing temperature.
- Increased broadening of both gain and absorption transition reduce the gain peak height.
- The reason might be increased scattering from ionised dopants.

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